Introduction to Electronics Task

Task 2:

Link of Recording videos:

https://drive.google.com/drive/u/6/folders/1QA2X4cqjQP7ythlice8H7O5VR9b-prB

Overvoltage Protection Circuits Using NPN and PNP BJTs

Introduction

Overvoltage protection is essential in electronic circuits to safeguard sensitive components from voltage spikes. This report presents the design, simulation, and comparison of NPN and PNP BJT overvoltage protection circuits using BC847C and BC557C transistors, along with a BZX84C12L Zener diode for the PNP circuit, in LTspice.

Circuit Design

NPN BJT Overvoltage Protection Circuit

1. Components:

- NPN BJT (BC847C)
- $_{\circ}$ Resistor (e.g., 1k Ω)

2. Circuit Description:

- The circuit uses a BC847C NPN transistor to shunt excess voltage away from the protected load.
- A resistor is connected between the base and the input voltage to control the base current.

When the input voltage exceeds the transistor's baseemitter threshold voltage, the transistor turns on, creating a low-resistance path from the collector to the emitter, shunting the excess voltage.

PNP BJT Overvoltage Protection Circuit

1. Components:

- PNP BJT (BC557C)
- Zener Diode (BZX84C12L, 12V)
- $_{\circ}$ Resistor (e.g., 1k Ω)

2. Circuit Description:

- The circuit uses a BC557C PNP transistor and a BZX84C12L
 Zener diode to shunt excess voltage away from the protected load.
- The Zener diode is connected in reverse bias to the base of the PNP transistor.
- When the input voltage exceeds the Zener breakdown voltage, the Zener diode conducts, allowing current to flow to the base of the PNP transistor.
- This turns on the transistor, creating a low-resistance path from the emitter to the collector, shunting the excess voltage.

Simulation Setup

NPN BJT Overvoltage Protection Circuit Simulation

1. Steps:

- o Open LTspice and create a new schematic.
- Place the BC847C NPN transistor and the resistor.

- Connect the resistor to control the base current.
- Apply a variable input voltage source.
- Run the simulation to observe the voltage across the protected load.

PNP BJT Overvoltage Protection Circuit Simulation

1. Steps:

- Open LTspice and create a new schematic.
- Place the BC557C PNP transistor, BZX84C12L Zener diode, and the resistor.
- Connect the Zener diode in reverse bias to the base of the PNP transistor.
- Connect the resistor to control the base current.
- Apply a variable input voltage source.
- Run the simulation to observe the voltage across the protected load.

Results and Discussion

NPN BJT Overvoltage Protection Circuit

Simulation Results:

- The circuit activates when the input voltage exceeds the transistor's base-emitter threshold voltage.
- The BC847C transistor conducts, creating a lowresistance path and clamping the voltage across the protected load.

Observations:

- The response time of the BC847C transistor is quick, effectively protecting the load.
- The clamping voltage is slightly above the base-emitter threshold voltage due to the V_BE drop of the transistor.

PNP BJT Overvoltage Protection Circuit

Simulation Results:

- The circuit activates when the input voltage exceeds the Zener breakdown voltage.
- The BC557C transistor conducts, creating a lowresistance path and clamping the voltage across the protected load.

Observations:

- The response time of the BC557C transistor is quick, effectively protecting the load.
- The clamping voltage is slightly above the Zener breakdown voltage due to the V_EB drop of the transistor.

Comparative Analysis

• Response Time:

Both BC847C and BC557C transistors provide fast response times, essential for overvoltage protection.

Voltage Clamping:

The NPN circuit clamps the voltage slightly above the baseemitter threshold voltage, while the PNP circuit clamps the voltage slightly above the Zener breakdown voltage.

Current Handling:

BC847C and BC557C transistors are similar in current handling, suitable for low to moderate current applications.

• Polarity:

The NPN circuit (BC847C) is used for positive overvoltage protection, while the PNP circuit (BC557C with BZX84C12L) is used for negative overvoltage protection.

Conclusion

Both NPN and PNP BJT overvoltage protection circuits effectively protect against voltage spikes by clamping the voltage to a safe level. The NPN circuit using BC847C provides protection without a Zener diode, while the PNP circuit using BC557C and BZX84C12L offers effective clamping with the addition of a Zener diode. The choice between these circuits depends on the specific application requirements, such as the polarity of the voltage to be protected. Both designs offer quick response times and reliable protection, making them suitable for various electronic applications.